onsemi

Plastic Infrared Light Emitting Diode

QEE113

Description

The QEE113 is a 940 nm GaAs LED encapsulated in a medium wide angle, plastic sidelooker package.

Features

- $\lambda = 940 \text{ nm}$
- Package Type = Sidelooker
- Chip Material = GaAs
- Matched Photosensor: QSE113
- Medium Wide Emission Angle, 50°
- Package Material: Clear Epoxy
- High Output Power
- Gray Dot Marking on the Top Side
- This is a Pb–Free Device

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) (Note 2), (Note 3), (Note 4)	240 for 5 s	°C
T _{SOL-F}	Soldering Temperature (Flow) (Note 2), (Note 3)	260 for 10 s	°C
١ _F	Continuous Forward Current	50	mA
V _R	Reverse Voltage	5	V
PD	Power Dissipation (Note 1)	100	mW

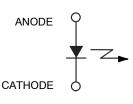
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. RMA flux is recommended.

- 3. Methanol or Isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing.

SIDELOOKER EMITTER CASE 100CJ





ORDERING INFORMATION

Device	Package	Shipping [†]
QEE113	SIDELOOKER EMITTER (Pb-Free)	500 units / Bulk Bag
QEE113E3R0	SIDELOOKER EMITTER (Pb-Free)	2000 units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, <u>BRD8011/D</u>.

^{1.} Derate power dissipation linearly 1.33 mW/°C above 25°C.

QEE113

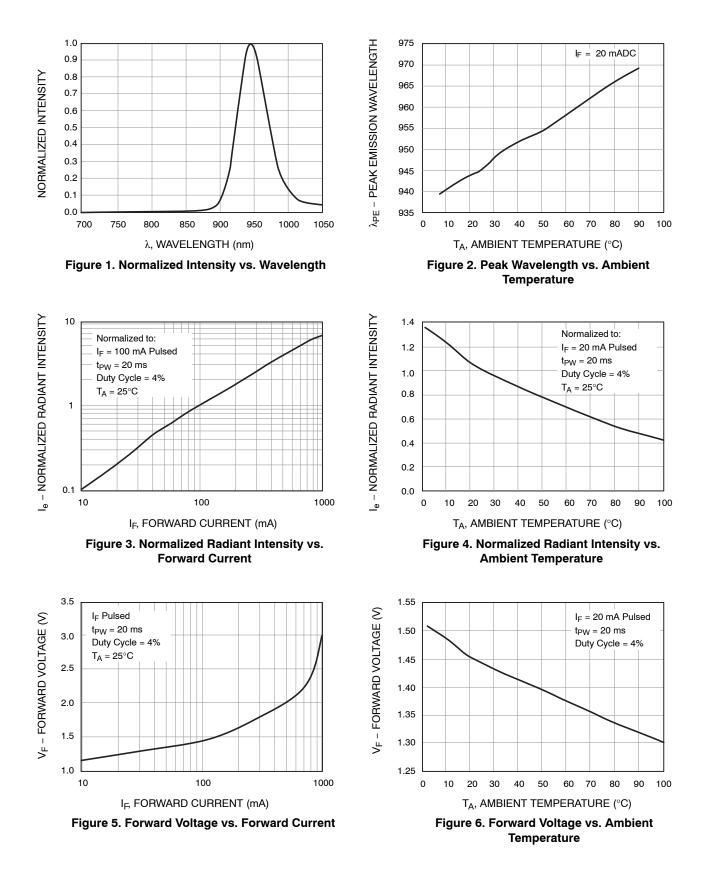
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
λ_{PE}	Peak Emission Wavelength	I _F = 20 mA	-	945	-	nm
TC_{λ}	Temperature Coefficient		-	0.3	-	nm/°C
2\Theta ¹ /2	Emission Angle	I _F = 100 mA	-	50	-	0
V _F	Forward Voltage	I _F = 100 mA, tp = 20 ms	-	-	1.5	V
TC _{VF}	Temperature Coefficient		-	-2	-	mV/°C
I _R	Reverse Current	V _R = 5 V	-	-	10	μA
Ι _Ε	Radiant Intensity	I _F = 100 mA, tp = 20 ms	3	7.5	12	mW/sr
TCIE	Temperature Coefficient		-	-0.7	-	%/°C
t _r	Rise Time	I _F = 100 mA	-	800	-	ns
t _f	Fall Time]	-	800	-	ns
Cj	Junction Capacitance	V _R = 0 V	-	14	_	pF

ELECTRICAL / OPTICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

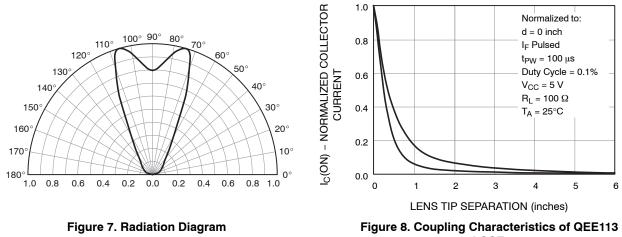
QEE113

TYPICAL PERFORMANCE CHARACTERISTICS



QEE113

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

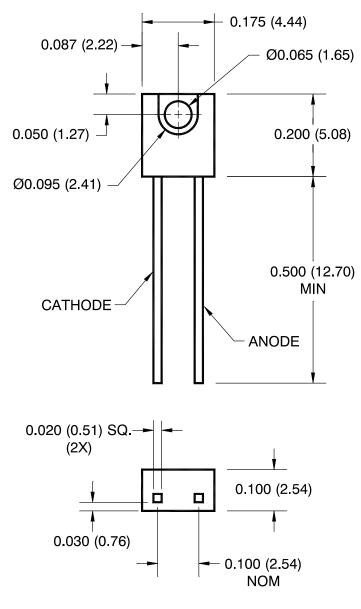


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SIDELOOKER EMITTER CASE 100CJ ISSUE O

DATE 30 NOV 2016



Notes:

1. Dimensions for all drawings are in inches (mm).

2. Tolerance of ±0.010 (0.25) on all non-nominal dimensions unless otherwise specified.

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